

BIPOLAR ANALOG INTEGRATED CIRCUIT $\mu PC4741$

HIGH PERFORMANCE QUAD OPERATIONAL AMPLIFIER

DESCRIPTION

The μ PC4741 consists of four independent frequency compensated operational amplifiers featuring higher speed, broader band than general purpose type as 741. The μ PC4741 is most appropriate for AC signal amplifier applications such as active filters or pulse amplifiers.

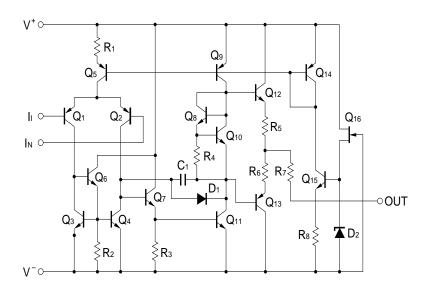
FEATURES

- Internal frequency compensation
- Low noise
- Output short circuit protection

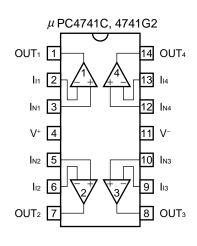
ORDERING INFORMATION

Part Number	Package
μΡC4741C	14-pin plastic DIP (7.62 mm (300))
μPC4741C(5)	14-pin plastic DIP (7.62 mm (300))
μPC4741G2	14-pin plastic SOP (5.72 mm (225))
μPC4741G2(5)	14-pin plastic SOP (5.72 mm (225))

EQUIVALENT CIRCUIT (1/4 Circuit)



PIN CONFIGURATION (Top View)



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The mark \star shows major revised points.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Par	ameter	Symbol	Ratings	Unit
Voltage between V^+ a	nd V ^{- Note1}	$V^+ - V^-$	-0.3 to +40	V
Differential Input Volta	age	Vid	±30	V
Input Voltage Note2		Vı	V^{-} =0.3 to V^{+} =0.3	V
Output Voltage Note3		Vo	V^{-} =0.3 to V^{+} =0.3	V
Power Dissipation	C Package Note4	Ρτ	570	mW
	G2 Package Note5		550	mW
Output Short Circuit D	Ouration Note6		10	sec
Operating Ambient Te	emperature	TA	-20 to +80	°C
Storage Temperature		Tstg	-55 to +125	°C

Notes 1. Reverse connection of supply voltage can cause destruction.

- 2. The input voltage should be allowed to input without damage or destruction. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The normal operation will establish when the both inputs are within the Common Mode Input Voltage Range of electrical characteristics.
- 3. This specification is the voltage which should be allowed to supply to the output terminal from external without damage or destructive. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The output voltage of normal operation will be the Output Voltage Swing of electrical characteristics.
- 4. Thermal derating factor is -7.6 mW/°C when ambient temperature is higher than 50°C.
- 5. Thermal derating factor is -5.5 mW/°C when ambient temperature is higher than 25°C.
- 6. Pay careful attention to the total power dissipation not to exceed the absolute maximum ratings, Note 4 and Note 5.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V^{\pm}	±4		±16	V

µPC4741C, 4741G2

ELECTRICAL CHARACTERISTICS (T_A = 25°C, V[±] = \pm 15 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input Offset Voltage	Vio	$Rs \le 100 \Omega$		±1.0	±5.0	mV
Input Offset Current Note	lio			±30	±50	nA
Input Bias Current Note	Ів			70	300	nA
Large Signal Voltage Gain	Av	$R_{\text{L}} \geq 2 \; k \Omega$, Vo = ±10 V	25,000	50,000		
Power Consumption	Pd	Io = 0 A, All Amplifiers		150	210	mW
Common Mode Rejection Ratio	CMR		80	100		dB
Supply Voltage Rejection Ratio	SVR			50	100	μV/ V
Maximum Output Voltage	Vom	R∟≥ 10 kΩ	±12	±13.7		V
Maximum Output Voltage	Vom	$R_{L} \ge 2 \ k\Omega$	±10	±12.5		V
Common Mode Input Voltage Range	Vicм		±12	±14		V
Slew Rate	SR	Av = 1		1.6		V/ μs
Input Equivalent Noise Voltage Density	en	f = 1 kHz		9		nV/√Hz
Channel Separation		f = 10 kHz		108		dB

Note Input bias currents flow out from IC. Because each currents are base current of PNP-transistor on input stage.

μPC4741C (5), 4741G2 (5)

ELECTRICAL CHARACTERISTICS (T_A = 25° C, V[±] = ± 15 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input Offset Voltage	Vio	$R_{s} \leq 100 \ \Omega$		±1.0	±2.0	mV
Input Offset Current Note	lio			±30	±50	nA
Input Bias Current Note	Ів				100	nA
Large Signal Voltage Gain	Av	$R_L \geq 2 \; k \Omega$, $V_O = \pm 10 \; V$	28,000	50,000		
Power Consumption	Pd	lo = 0 A, All Amplifiers		150	210	mW
Common Mode Rejection Ratio	CMR		85	90		dB
Supply Voltage Rejection Ratio	SVR				50	μV/ V
Maximum Output Voltage	Vom	R∟≥ 10 kΩ	±12.5	±13.7		V
Maximum Output Voltage	Vom	$R_L \ge 2 \ k\Omega$	±11	±12.5		V
Common Mode Input Voltage Range	VICM		±13	±14		V
Slew Rate	SR	Av = 1		1.6		V/ μs
Input Equivalent Noise Voltage Density	en	f = 1 kHz		9		nV/√Hz
Channel Separation		f = 10 kHz		108		dB

Note Input bias currents flow out from IC. Because each currents are base current of PNP-transistor on input stage.

MEASUREMENT CIRCUIT

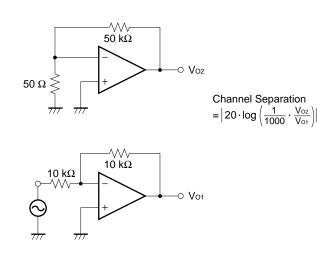
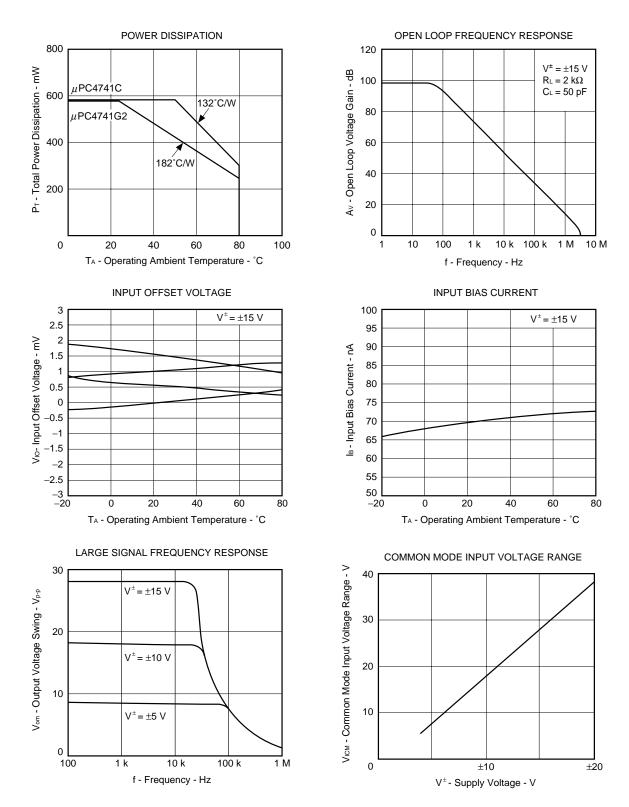
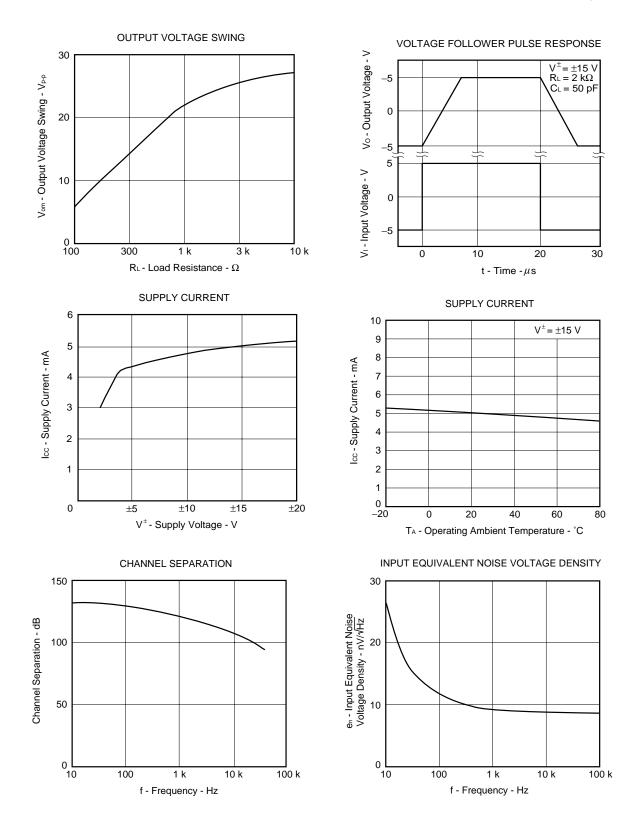


Fig.1 Channel Separation Measurement Circuit

TYPICAL PERFORMANCE CHARACTERISTICS (TA = 25°C, TYP.)

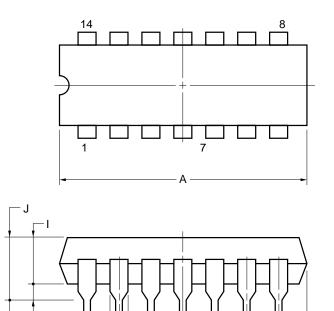
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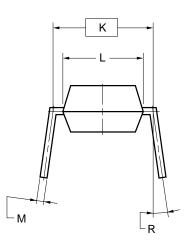




* PACKAGE DRAWINGS (Unit: mm)

14-PIN PLASTIC DIP (7.62 mm (300))





NOTES

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-G

1. Each lead centerline is located within 0.25 mm of its true position (T.P.) at maximum material condition.

NM

С

-В

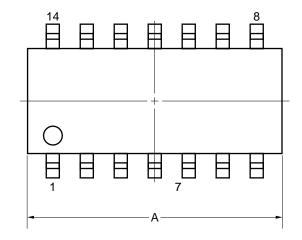
2. Item "K" to center of leads when formed parallel.

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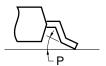
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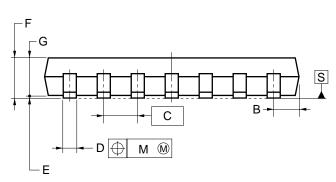
ITEM	MILLIMETERS
А	19.22±0.2
В	2.14 MAX.
С	2.54 (T.P.)
D	0.50±0.10
F	1.32±0.12
G	3.6±0.3
Н	0.51 MIN.
I	3.55
J	4.3±0.2
К	7.62 (T.P.)
L	6.4±0.2
М	$0.25^{+0.10}_{-0.05}$
N	0.25
R	0~15°
F	P14C-100-300B1-3

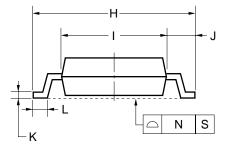
14-PIN PLASTIC SOP (5.72 mm (225))



detail of lead end







NOTE

Each lead centerline is located within 0.1 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
А	10.2±0.26
В	1.42 MAX.
С	1.27 (T.P.)
D	$0.42\substack{+0.08\\-0.07}$
E	0.1±0.1
F	1.59 ^{+0.21}
G	1.49
Н	6.5±0.2
I	4.4±0.1
J	1.1±0.16
к	$0.17\substack{+0.08\\-0.07}$
L	0.6±0.2
М	0.1
N	0.10
Р	$3^{\circ}^{+7^{\circ}}_{-3^{\circ}}$

S14GM-50-225B, C-6

***** RECOMMENDED SOLDERING CONDITIONS

When soldering this product, it is highly recommended to observe the conditions as shown below. If other soldering processes are used, or if the soldering is performed under different conditions, please make sure to consult with our sales offices.

For more details, refer to below our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL"(C10535E).

Type of Surface Mount Device

μPC4741G2, 4741G2(5): 14-pin plastic SOP (5.72 mm (225))

Process	Conditions	Symbol
Infrared Ray Reflow	Peak temperature: 235°C or below (Package surface temperature), Reflow time: 30 seconds or less (at 210°C or higher), Maximum number of reflow processes: 3 time.	IR35-00-3
Vapor Phase Soldering	Peak temperature: 215°C or below (Package surface temperature), Reflow time: 40 seconds or less (at 200°C or higher), Maximum number of reflow processes: 3 time.	VP15-00-3
Wave Soldering	Solder temperature: 260°C or below, Flow time: 10 seconds or less, Maximum number of flow processes: 1 time, Pre-heating temperature: 120°C or below (Package surface temperature).	WS60-00-1
Partial Heating Method	Pin temperature: 300°C or below, Heat time: 3 seconds or less (Per each side of the device).	-

Caution Apply only one kind of soldering condition to a device, except for "partial heating method", or the device will be damaged by heat stress.

Type of Through-hole Device

μPC4741C, 4741C(5): 14-pin plastic DIP (7.62 mm (300))

Process	Conditions
Wave Soldering (only to leads)	Solder temperature: 260°C or below, Flow time: 10 seconds or less.
Partial Heating Method	Pin temperature: 300°C or below, Heat time: 3 seconds or less (per each lead).

Caution For through-hole device, the wave soldering process must be applied only to leads, and make sure that the package body does not get jet soldered.

[MEMO]

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